

## Differential Output (VC)TCXO

## 10MHz to 1500MHz

- 1.0pS RMS integrated phase jitter
- Quick turnaround, low-cost TCXO
- Miniature package sizes
- Supply voltage 2.5V or 3.3 VDC
- Frequency stability from  $\pm 1$ ppm over  $-40$  to  $+85^{\circ}\text{C}$



### DESCRIPTION

(V)EMQF series TCXOs are packaged in miniature SMD packages, available with 6 pad LVPECL or LVDS complementary outputs, or 4-pad CMOS outputs. With characteristic low current consumption, an integrated phase jitter performance of 1.0 pS RMS and a quick delivery time, these provide an excellent solution for both prototypes and low-cost volume production.

### GENERAL SPECIFICATION

Output Logic	CMOS	PECL	LVDS
Packages	(V)EMQF326T, (V)EMQF574T, (V)EMQF576T	(V)EMQF326P, (V)EMQF576P	(V)EMQF326D, (V)EMQF576D
Supply Voltage, Vdd	+2.5V $\pm 5\%$ or +3.3V $\pm 5\%$	+2.5V $\pm 5\%$ or +3.3V $\pm 5\%$	+2.5V $\pm 5\%$ or +3.3V $\pm 5\%$
Available Frequency Range	10MHz~250MHz	10MHz~1,500MHz	10MHz~1,500MHz
Output Load	15pF	50 $\Omega$ into Vcc-2V, or Thévenin Equivalent	100 $\Omega$
Output Logic 'High'	90% of Vdd	Vdd-1.03 (min.), Vdd-0.6 (max.)	1.4V (typ.), 1.6V (max.)
Output Logic 'Low'	10% of Vdd	Vdd-1.85 (min.), Vdd-1.6 (max.)	1.1V (typ.), 0.9V (max.)
Current Consumption (max.) @Vdd=+2.5V	50MHz: 34mA	156MHz: 46mA	156MHz: 32mA
	125MHz: 38mA	600MHz: 50mA	600MHz: 38mA
	200MHz: 40mA	1,000MHz: 60mA	1,000MHz: 44mA
Current Consumption (max.) @Vdd=+3.3V	50MHz: 36mA	156MHz: 50mA	156MHz: 35mA
	125MHz: 40mA	600MHz: 55mA	600MHz: 40mA
	200MHz: 44mA	1,000MHz: 62mA	1,000MHz: 46mA
Current With Output Disabled	18mA (typ.)	18mA (typ.)	18mA (typ.)
Rise/Fall Time	1.5nsec. (typ.), 3.0nsec. (max.)	0.2nsec. (typ.), 0.5nsec.(max.)	0.2nsec. (typ.), 0.4nsec. (max.)
	Tr/Tf: 10% to 90% of waveform		Tr/Tf: 20% to 80% of waveform
Initial Calibration Tolerance	$\pm 1.0$ ppm (max.) at $+25 \pm 2^{\circ}\text{C}$ for 3.2x2.5mm packages		
	$\pm 2.0$ ppm (max.) at $+25 \pm 2^{\circ}\text{C}$ for 5.0x7.0mm packages		
Frequency Stability	Temperature	$\pm 2.0$ ppm over $-40^{\circ}\text{C}$ $+85^{\circ}\text{C}$ standard for programmable TCXO, $\pm 1.0$ ppm available	
	Aging @+25 $^{\circ}\text{C}$	$\pm 2.0$ ppm (max.) first year; $\pm 1.0$ ppm (max.) over 10 years	
	Voltage Change	$\pm 0.2$ ppm (max.) for a $\pm 5\%$ input voltage change	
	Load Change	$\pm 0.2$ ppm (max.), for a $\pm 10\%$ load condition change	
	Reflow	$\pm 1.0$ ppm (max.), 1 reflow and measured 24hrs afterwards	
Duty Cycle	50 $\pm 5\%$		
Start-up Time	5msec.(max.)		
Storage Temperature	$-55^{\circ}\text{C}$ to $125^{\circ}\text{C}$		
RMS Jitter [12kHz ~ 20MHz]	1.0psec. (typ.)		

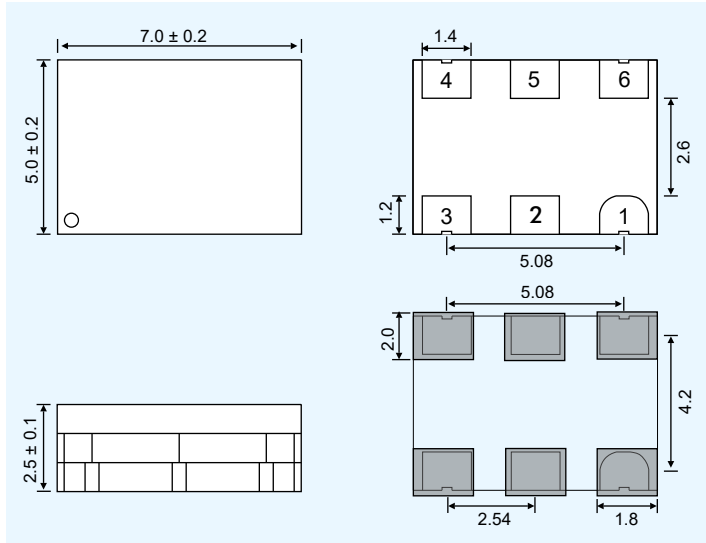
Phase Noise [dBc/Hz (typ.)]	Offset	10Hz	100Hz	1kHz	10kHz	100kHz	1MHz	10MHz
	156.250MHz	-65	-92	-108	-114	-117	-139	-147
	212.500MHz	-61	-90	-106	-110	-112	-133	-142
	312.500MHz	-51	-79	-97	-102	-103	-125	-134

### VOLTAGE CONTROL FUNCTION

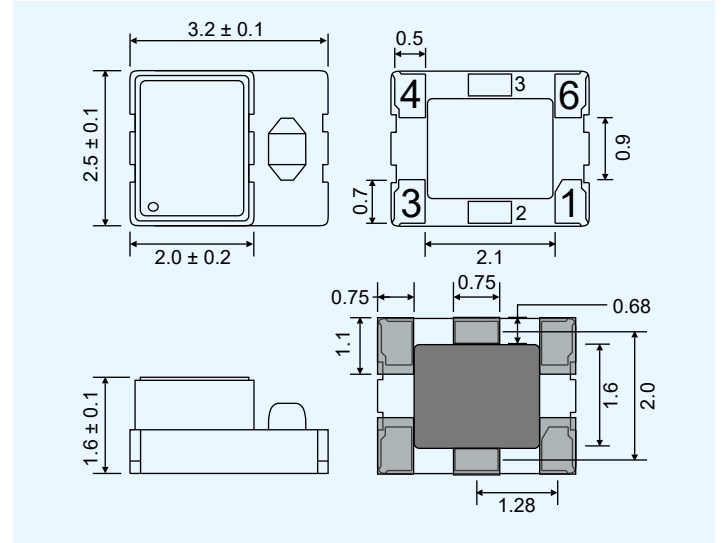
Control Voltage Function on Pad 1		Output Enable Function on Pad 2	
Control Voltage Centre and Range	+1.5 $\pm 1.0$ V for both Vdd = 2.5V or 3.3V	OE Control on Pad 2	70% of Vdd (min.) to enable output (Do not leave open)
Frequency Pulling Range	$\pm 8$ ppm (min.)		30% of Vdd (max.) to disable output
Linearity	1% (typ.); 10%(max.)	Linearity	1% (typ.); 10%(max.)
Absolute Voltage	4.0V (max.)	Output Enable/Disable Time	200nsec. (max.) / 50nsec.(max.)
Transfer Function	Positive Transfer		
Input Impedance	770K $\Omega$ (typ.)		

**OUTLINES AND DIMENSIONS**

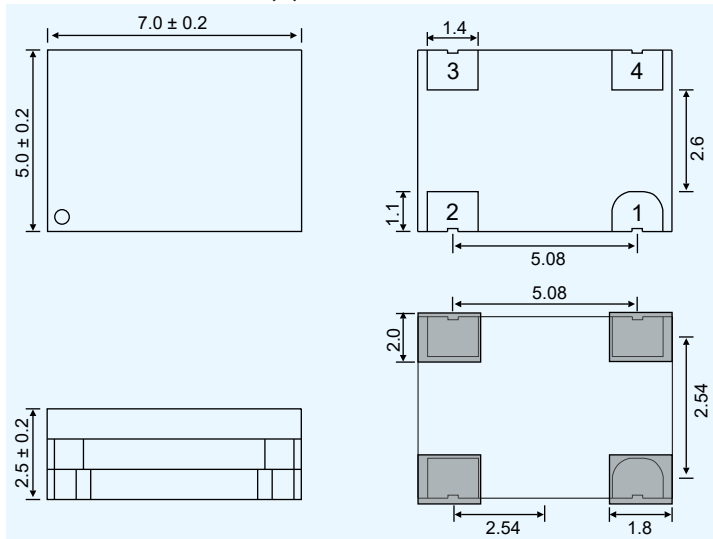
**(V)EMQF576D, (V)EMQF576T, (V)EMQF576P**



**(V)EMQF326T, (V)EMQF326D, (V)EMQF326P**



**(V)EMQF574T**



**Pad Connection**

For 6 Pad

- Pad 1: TCXO: No Connection  
VCTCXO: Control Voltage
- Pad 2: Enable/Disable
- Pad 3: Ground
- Pad 4: CMOS: Output  
PECL/LVDS: Differential
- Pad 5: CMOS: No Connection  
PECL/LVDS: Differential
- Pad 6: Supply Voltage

**Pad Connection**

For 4 Pad

- Pad 1: TCXO: No Connection  
VCTCXO: Control Voltage
- Pad 2: Ground
- Pad 3: Output
- Pad 4: Supply Voltage

**PART NUMBERS**

Example:

**VEMQF576P33-50.000-2.0/-40+85**

Series Description  
TCXO = EMQF  
VCTCXO = VEMQF

Package Size  
576: 5.0x7.0mm, 6 Pad  
574: 5.0x7.0mm, 4 Pad  
326: 3.2x2.5mm, 6 Pad

Output Type  
P = LVPECL  
D = LVDS  
T = CMOS

Supply Voltage  
3.3V = 33  
2.5V = 25

Frequency (MHz)

Stability over OTR ( $\pm$ ppm)

Operating Temperature Range (OTR) ( $^{\circ}$ C)